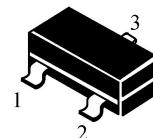


**SOT-23 Bipolar Transistor 双极型三极管****SOT-23****■ Features 特点****NPN Low equivalent on-resistance 低等效电阻**

1. BASE
2. Emitter
3. COLLECTOR

**■ Absolute Maximum Ratings 最大额定值**

| Characteristic 特性参数                         | Symbol 符号                   | Rat 额定值        | Unit 单位 |
|---|-----------------------------|----------------|---------|
| Collector-Base Voltage 集电极基极电压              | $V_{CBO}$                   | 120            | V       |
| Collector-Emitter Voltage 集电极发射极电压          | $V_{CEO}$                   | 100            | V       |
| Emitter-Base Voltage 发射极基极电压                | $V_{EBO}$                   | 5              | V       |
| Collector Current 集电极电流                     | $I_C$                       | 1000           | mA      |
| Power dissipation 耗散功率                      | $P_C(T_a=25^\circ\text{C})$ | 250            | mW      |
| Thermal Resistance Junction-Ambient 热阻      | $R_{\theta JA}$             | 500            | °C/W    |
| Junction and Storage Temperature<br>结温和储藏温度 | $T_J, T_{stg}$              | -55 to +150 °C |         |

**■ Device Marking 产品打标**

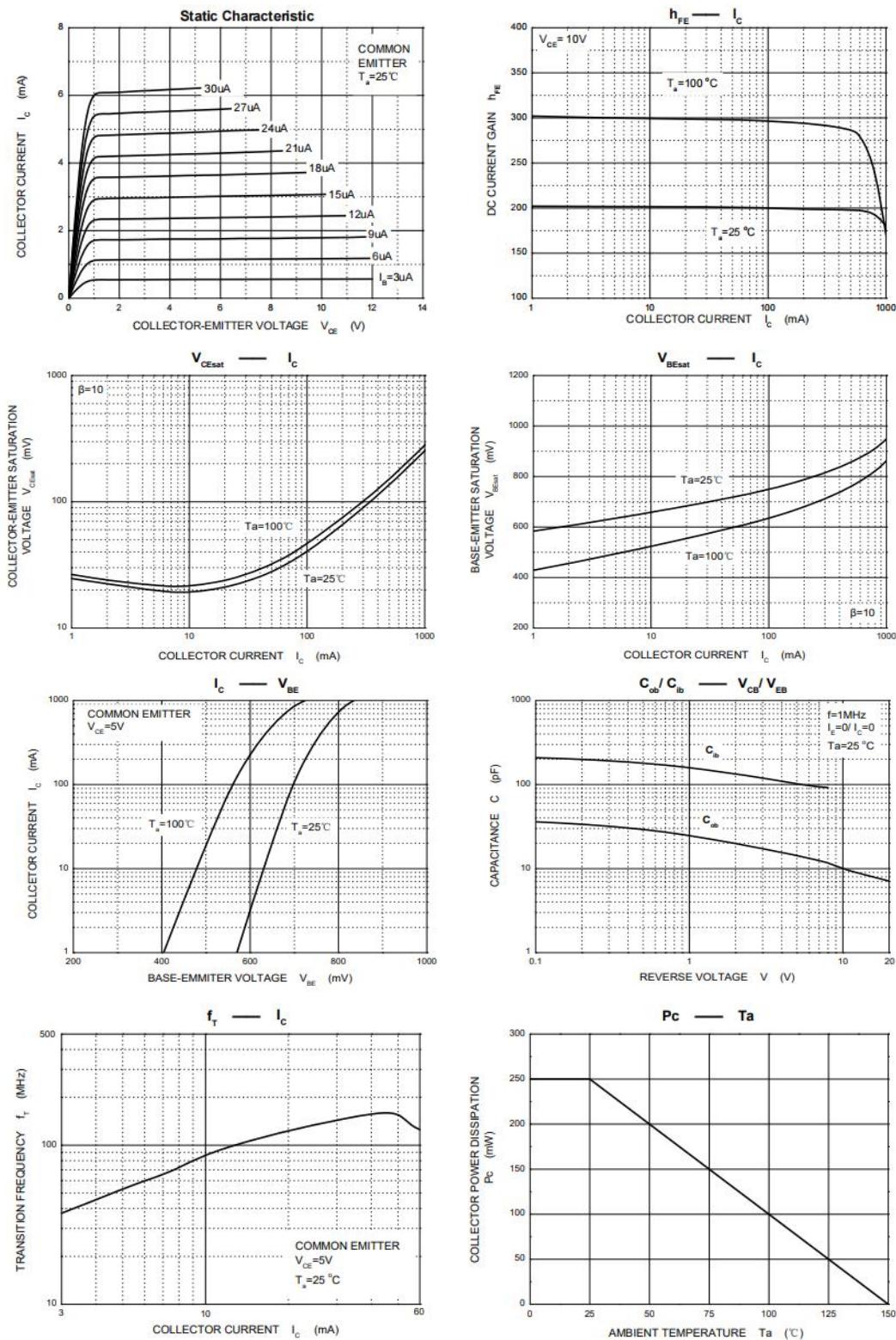
FMMT493=493

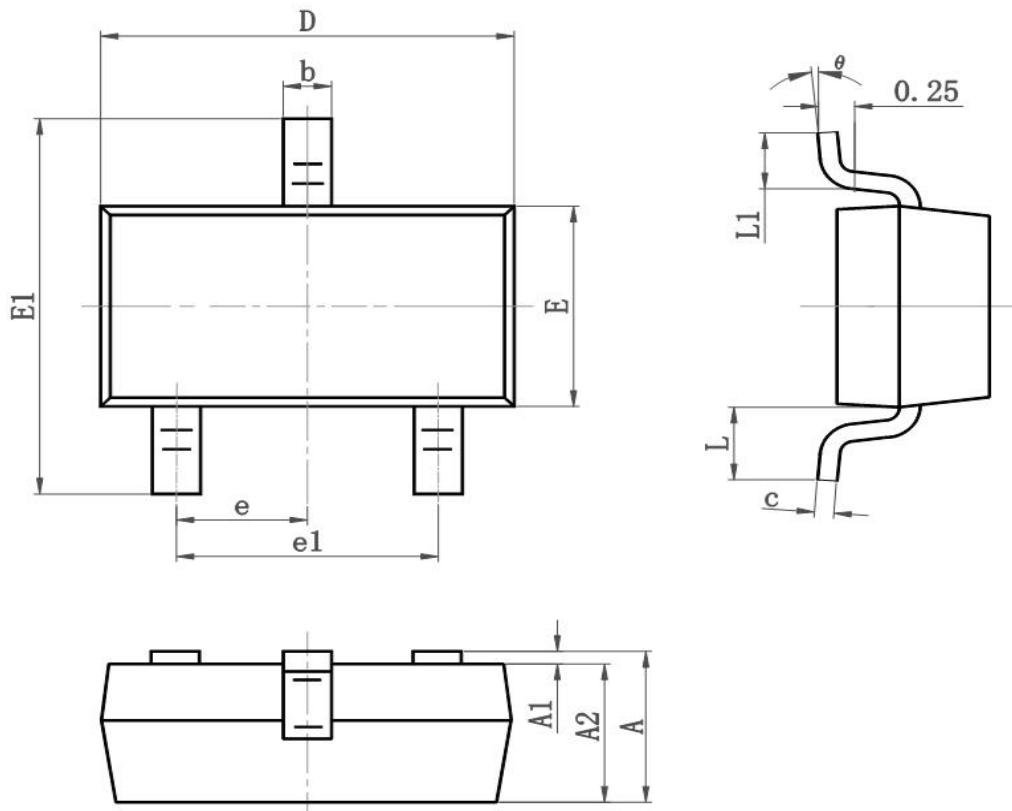
**■ Electrical Characteristics 电特性**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic<br>特性参数   | Symbol<br>符号  | Min<br>最小值             | Type<br>典型值 | Max<br>最大值 | Unit<br>单位 |
|--|---------------|------------------------|-------------|------------|------------|
| Collector-Base Breakdown Voltage<br>集电极基极击穿电压( $I_C = 100\mu A$ , $I_E = 0$ )  | $BV_{CBO}$    | 120                    | —           | —          | V          |
| Collector-Emitter Breakdown Voltage<br>集电极发射极击穿电压( $I_C = 10mA$ , $I_B = 0$ )  | $BV_{CEO}$    | 100                    | —           | —          | V          |
| Emitter-Base Breakdown Voltage<br>发射极基极击穿电压( $I_E = 100\mu A$ , $I_C = 0$ )  | $BV_{EBO}$    | 5                      | —           | —          | V          |
| Collector-Base Leakage Current<br>集电极基极漏电流( $V_{CB} = 100V$ , $I_E = 0$ )  | $I_{CBO}$     | —                      | —           | 100        | nA         |
| Collector-Emitter Leakage Current<br>集电极发射极漏电流( $V_{CE} = 100V$ , $V_{BE} = 0V$ )  | $I_{CES}$     | —                      | —           | 100        | nA         |
| Emitter-Base Leakage Current<br>发射极基极漏电流( $V_{EB} = 4V$ , $I_C = 0$ )  | $I_{EBO}$     | —                      | —           | 100        | nA         |
| DC Current Gain( $V_{CE} = 10V$ , $I_C = 1mA$ )<br>直流电流增益( $V_{CE} = 10V$ , $I_C = 250mA$ )<br>( $V_{CE} = 10V$ , $I_C = 500mA$ )<br>( $V_{CE} = 10V$ , $I_C = 1000mA$ ) | $H_{FE}$      | 100<br>100<br>60<br>20 | —           | 300        |            |
| Collector-Emitter Saturation Voltage<br>集电极发射极饱和压降<br>( $I_C = 500mA$ , $I_B = 50mA$ )<br>( $I_C = 1000mA$ , $I_B = 100mA$ )   | $V_{CE(sat)}$ | —                      | —           | 0.3<br>0.6 | V          |
| Base-Emitter Saturation Voltage<br>基极发射极饱和压降<br>( $I_C = 1000mA$ , $I_B = 100mA$ )   | $V_{BE(sat)}$ | —                      | —           | 1.15       | V          |
| Base-Emitter On Voltage<br>基极发射极导通电压<br>( $V_{CE} = 10V$ , $I_C = 1000mA$ )  | $V_{BE(on)}$  | —                      | —           | 1          | V          |
| Transition Frequency<br>特征频率( $V_{CE} = 10V$ , $I_C = 50mA$ )  | $f_T$         | 150                    | —           | —          | MHz        |
| Output Capacitance<br>输出电容( $V_{CB} = 10V$ , $I_E = 0$ , $f = 1MHz$ )  | $C_{ob}$      | —                      | 10          | —          | pF         |

■Typical Characteristic Curve 典型特性曲线



**■Dimension 外形封装尺寸**

| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 0.900                     | 1.150 | 0.035                | 0.045 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.900                     | 1.050 | 0.035                | 0.041 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.080                     | 0.150 | 0.003                | 0.006 |
| D      | 2.800                     | 3.000 | 0.110                | 0.118 |
| E      | 1.200                     | 1.400 | 0.050                | 0.055 |
| E1     | 2.250                     | 2.550 | 0.089                | 0.100 |
| e      | 0.900                     | 1.00  | 0.035                | 0.039 |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.500                     | 0.600 | 0.020                | 0.024 |
| L1     | 0.300                     | 0.500 | 0.012                | 0.020 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |